

ZXMN6A25N8 60V SO8 N-channel enhancement mode MOSFET

Summary

V _{(BR)DSS}	R _{DS(on)} (Ω)	I _D (A)
60	0.050 @ V _{GS} =10V	7.0
	0.070 @ V _{GS} =4.5V	



Description

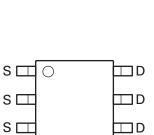
This new generation Trench MOSFET from Zetex features low on-resistance and fast switching, making it ideal for high efficiency power management applications.

Features

- · Low on-resistance
- · Fast switching speed
- · Low gate drive
- SO8 package

Applications

- DC-DC Converters
- · Power management functions
- · Disconnect switches
- Motor control



 \Box D

Top view

 $G \square$

Ordering information

Device Reel size (inches)		Tape width (mm)	Quantity per reel	
ZXMN6A25N8TA	7	12	500	

Device marking

ZXMN6A25

Absolute maximum ratings

Parameter	Symbol	Limit	Unit
Drain-Source voltage	V_{DSS}	60	V
Gate-Source voltage	V_{GS}	± 20	V
Continuous Drain current @ V _{GS} = 10V; T _A =25°C (b)	I _D	5.7	Α
@ V_{GS} = 10V; T_A =70°C (b)		4.5	
@ V_{GS} = 10V; T_A =25°C (a)		4.3	
@ V_{GS} = 10V; T_L =25°C ^{(a)(d)}		7.0	
Pulsed Drain current (c)	I _{DM}	25.7	А
Continuous Source current (Body diode) (b)	I _S	4.1	А
Pulsed Source current (Body diode) (c)	I _{SM}	25.7	А
Power dissipation at T _A =25°C ^(a) Linear derating factor	P _D	1.56 12.5	W mW/°C
Power dissipation at T _A =25°C ^(b) Linear derating factor	P _D	2.8 22.2	W mW/°C
Power dissipation at T _L =25°C ^(d) Linear derating factor	P _D	4.14 33.1	W mW/°C
Operating and storage temperature range	T _j , T _{stg}	-55 to 150	°C

Thermal resistance

Parameter	Symbol	Value	Unit	
Junction to ambient ^(a)	$R_{ heta JA}$	80	°C/W	
Junction to ambient ^(b)	$R_{ heta JA}$	45	°C/W	
Junction to lead ^(d)	$R_{ heta JL}$	30.2	°C/W	

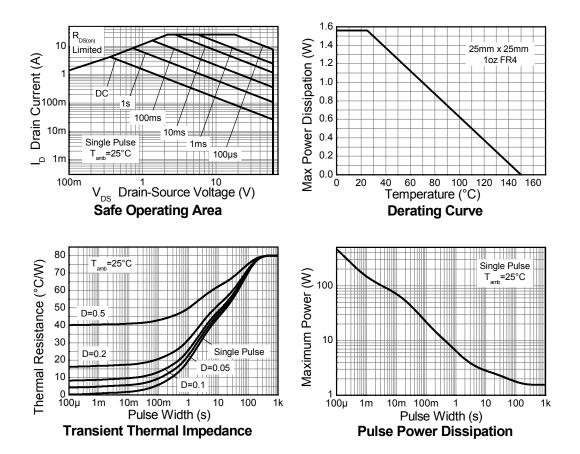
NOTES:

⁽a) For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions.

⁽b) Mounted on FR4 PCB measured at $t \le 10$ sec. (c) Repetitive rating on 25mm x 25mm FR4 PCB, D=0.02, pulse width 300us – pulse width limited by maximum junction temperature.

⁽d) Thermal resistance from junction to solder-point (at the end of the drain lead).

Thermal characteristics



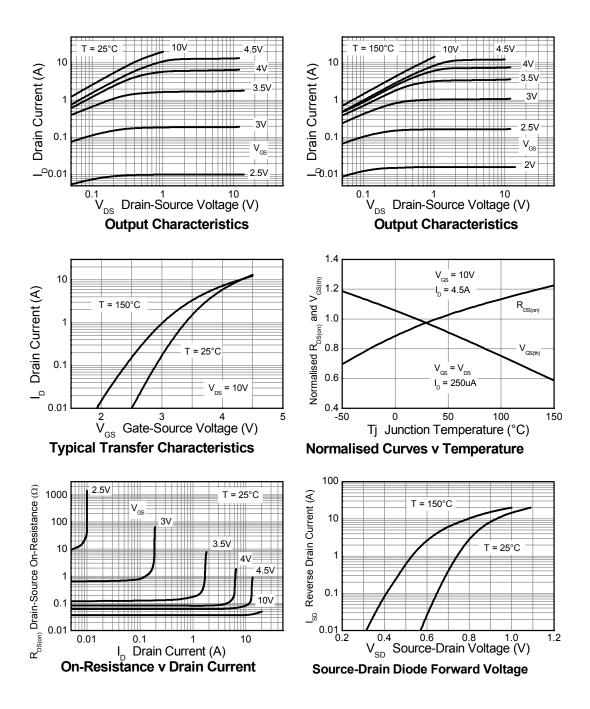
Electrical characteristics (at $T_{amb} = 25$ °C unless otherwise stated)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Static	,		,	•	ı	1
Drain-Source breakdown voltage	V _{(BR)DSS}	60			V	$I_D = 250 \mu A, V_{GS} = 0V$
Zero gate voltage drain current	I _{DSS}			1.0	μA	V _{DS} =60V, V _{GS} =0V
Gate-Body leakage	I _{GSS}			100	nA	V_{GS} =±20V, V_{DS} =0V
Gate-Source threshold voltage	V _{GS(th)}	1		3	V	I_D =250 μ A, V_{DS} = V_{GS}
Static Drain-Source on-state resistance (*)	R _{DS(on)}			0.050 0.070	Ω	V _{GS} = 10V, I _D = 3.6A V _{GS} = 4.5V, I _D = 3.0A
Forward Transconductance (*)(†)	9 _{fs}		10.2		S	V _{DS} = 15V, I _D = 4.5A
Dynamic ^(†)						
Input capacitance	C _{iss}		1063		pF	
Output capacitance	C _{oss}		104		pF	V _{DS} = 30V, V _{GS} =0V
Reverse transfer capacitance	C _{rss}		64		pF	f=1MHz
Switching (‡)(†)						
Turn-on-delay time	t _{d(on)}		3.8		ns	
Rise time	t _r		4.0		ns	V _{DD} = 30V, V _{GS} = 10V
Turn-off delay time	t _{d(off)}		26.2		ns	I _D = 1A R _G ≅ 6.0Ω,
Fall time	t _f		10.6		ns	-1 $G = 0.052$,
Gate charge	Qg		11.0		nC	V _{DS} = 30V, V _{GS} = 5V I _D = 4.5A
Total gate charge	Qg		20.4		nC	
Gate-Source charge	Q _{gs}		4.1		nC	V _{DS} = 30V, V _{GS} = 10V
Gate-Drain charge	Q _{gd}		5.1		nC	I _D = 4.5A
Source-Drain diode			ı		1	
Diode forward voltage (*)	V _{SD}		0.85	0.95	V	I _S = 5.5A,V _{GS} =0V
Reverse recovery time (‡)	t _{rr}		22.0		ns	L = 2.24 di/dt=4004/:-
Reverse recovery charge ^(‡)	Q _{rr}		21.4		nC	-I _S = 2.2A,di/dt=100A/μs

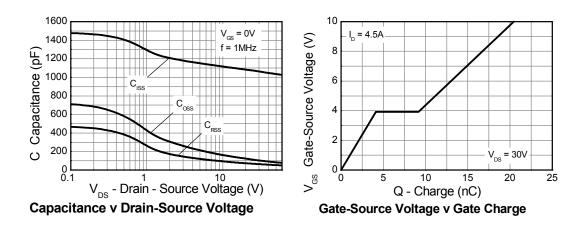
NOTES:

^(*) Measured under pulsed conditions. Pulse width $\leq 300 \mu s$; duty cycle $\leq 2\%$. (†)Switching characteristics are independent of operating junction temperature. (‡)For design aid only, not subject to production testing

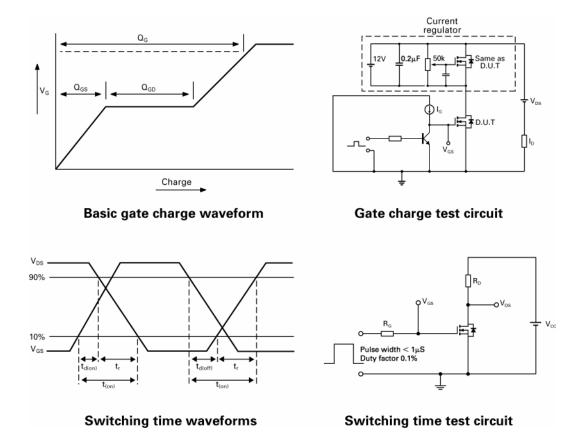
Typical characteristics



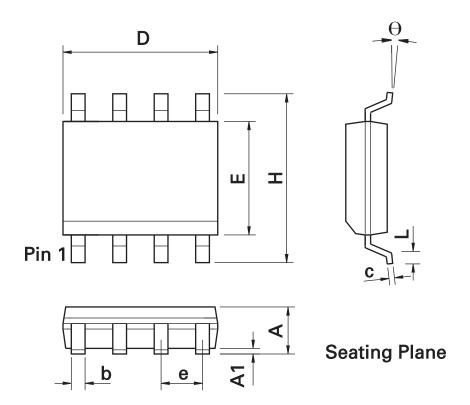
Typical characteristics



Test circuits



Package outline SO8



SO8 Package Information

DIM	Inc	hes	Millim	neters	DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
Α	0.053	0.069	1.35	1.75	е	0.050 BSC		1.27 BSC	
A1	0.004	0.010	0.10	0.25	b	0.013	0.020	0.33	0.51
D	0.189	0.197	4.80	5.00	С	0.008	0.010	0.19	0.25
Н	0.228	0.244	5.80	6.20	U	0°	8°	0°	8°
E	0.150	0.157	3.80	4.00	h	0.010	0.020	0.25	0.50
L	0.016	0.050	0.40	1.27	-	-	-	-	-

Note: Controlling dimensions are in inches. Approximate dimensions are provided in millimeters

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However, changes to the test conditions and specifications may occur, at any time and without notice.

However, changes to the test conditions and specifications may occur, at any time and without notice This term denotes an issued datasheet containing finalized specifications. However, changes to

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